MMBD330T1G, SMMBD330T1G, MMBD770T1G, SMMBD770T1G

Schottky Barrier Diodes

Schottky barrier diodes are designed primarily for high-efficiency UHF and VHF detector applications. Readily available to many other fast switching RF and digital applications. They are housed in the SOT-323/SC-70 package which is designed for low-power surface mount applications.

Features

- Extremely Low Minority Carrier Lifetime
- Very Low Capacitance
- Low Reverse Leakage
- Available in 8 mm Tape and Reel
- AEC Qualified and PPAP Capable
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant*

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Reverse Voltage MMBD330T1G, SMMBD330T1G MMBD770T1G, SMMBD770T1G	V _R	30 70	Vdc
Forward Continuous Current (DC)	IF	200	mA
Nonrepetitive Peak Forward Current (Note 1)	I _{FSM}	1.0	Α
Forward Power Dissipation T _A = 25°C	P _F	120	mW
Junction Temperature	T_{J}	-55 to +125	°C
Storage Temperature Range	T _{stg}	-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. 60 Hz Halfsine.



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SC-70/SOT-323 CASE 419



MARKING DIAGRAMS



XX = Specific Device Code

4T = MMBD330T1 5H = MMBD770T1 M = Date Code • Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation may vary depending upon the manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
MMBD330T1G	SC-70 (Pb-Free)	3,000/Tape & Reel
SMMBD330T1G	SC-70 (Pb-Free)	3,000/Tape & Reel
MMBD770T1G	SC-70 (Pb-Free)	3,000/Tape & Reel
SMMBD770T1G	SC-70 (Pb-Free)	3,000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

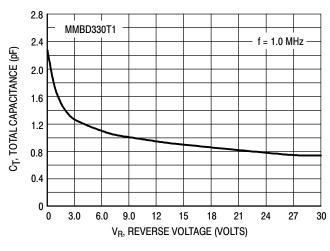
MMBD330T1G, SMMBD330T1G, MMBD770T1G, SMMBD770T1G

ELECTRICAL CHARACTERISTICS ($T_A = 25$ °C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Breakdown Voltage (I _B = 10 μA)	V _{(BR)R}				Volts
MMBD330T1G, SMMBD330T1G MMBD770T1G, SMMBD770T1G		30 70	- -	_ _	
Diode Capacitance (V _R = 15 Volts, f = 1.0 MHZ)	C _T				pF
MMBD330T1G, SMMBD330T1G (V _B = 20 Volts, f = 1.0 MHZ)		-	0.9	1.5	
MMBD770T1G, SMMBD770T1G		-	0.5	1.0	
Reverse Leakage (V _B = 25 V)	I _R				nAdc
MMBD330T1G, SMMBD330T1G (V _B = 35 V)		-	13	200	
MMBD770T1G, SMMBD770T1G		-	9.0	200	
Forward Voltage (I _F = 1.0 mAdc)	V _F				Vdc
MMBD330T1G, SMMBD330T1G (I _F = 10 mA)		- -	0.38 0.52	0.45 0.60	
(I _F = 1.0 mAdc) MMBD770T1G, SMMBD770T1G		_	0.42	0.50	
(I _F = 10 mA)		_	0.70	1.0	

MMBD330T1G, SMMBD330T1G, MMBD770T1G, SMMBD770T1G

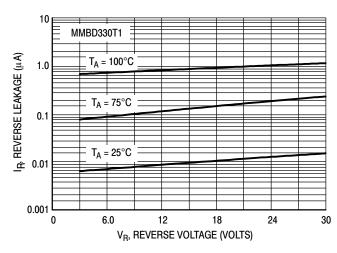
TYPICAL CHARACTERISTICS MMBD330T1G, SMMBD330T1G



SOO MMBD330T1 WMMBD330T1 WRAKAUER METHOD WKRAKAUER WKR

Figure 1. Total Capacitance

Figure 2. Minority Carrier Lifetime



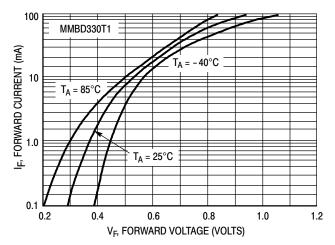
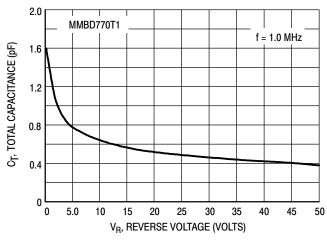


Figure 3. Reverse Leakage

Figure 4. Forward Voltage

MMBD330T1G, SMMBD330T1G, MMBD770T1G, SMMBD770T1G

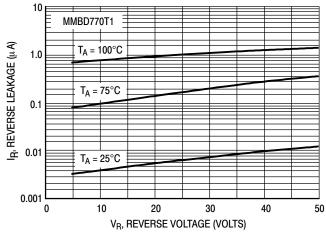
TYPICAL CHARACTERISTICS MMBD770T1G, SMMBD770T1G



500 MMBD770T1 τ , MINORITY CARRIER LIFETIME (ps) 400 KRAKAUER METHOD 300 200 100 0 0 10 20 30 50 100 90 IF, FORWARD CURRENT (mA)

Figure 5. Total Capacitance

Figure 6. Minority Carrier Lifetime



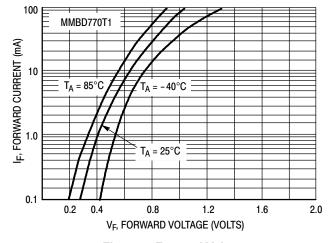


Figure 7. Reverse Leakage

Figure 8. Forward Voltage





SC-70 (SOT-323) CASE 419 ISSUE P

DATE 07 OCT 2021

NOTES:

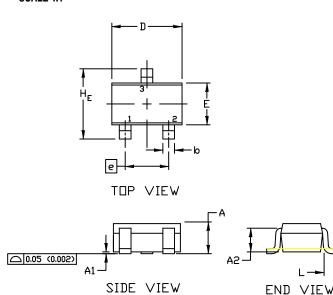
- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH

	MILLIMETERS				INCHES	
DIM	MIN.	N□M.	MAX.	MIN.	N□M.	MAX.
Α	0.80	0.90	1.00	0.032	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2	0.70 REF				0.028 BS	C
b	0.30	0.35	0.40	0.012	0.014	0.016
С	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.10	2.20	0.071	0.083	0.087
Ε	1.15	1.24	1.35	0.045	0.049	0.053
e	1.20	1.30	1.40	0.047	0.051	0.055
e1	0.65 BSC				0.026 BS	C
L	0.20	0.38	0.56	0.008	0.015	0.022
HE	2.00	2.10	2.40	0.079	0.083	0.095
				`		



For additional information on our Pb-Free strategy and soldering details, please download the IIN Semiconductor Soldering and Mounting Techniques Reference Manual, SILDERRM/D.

SOLDERING FOOTPRINT



GENERIC MARKING DIAGRAM



XX = Specific Device Code

M = Date Code

■ = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1: CANCELLED	STYLE 2: PIN 1. ANODE 2. N.C. 3. CATHODE	STYLE 3: PIN 1. BASE 2. EMITTER 3. COLLECTOR	STYLE 4: PIN 1. CATHODE 2. CATHODE 3. ANODE	STYLE 5: PIN 1. ANODE 2. ANODE 3. CATHODE	
STYLE 6:	STYLE 7:	STYLE 8:	STYLE 9:	STYLE 10:	STYLE 11:
PIN 1. EMITTER	PIN 1. BASE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. CATHODE
2. BASE	2. EMITTER	2. SOURCE	2. CATHODE	2. ANODE	2. CATHODE
3. COLLECTOR	3. COLLECTOR	3. DRAIN	3. CATHODE-ANODE	3. ANODE-CATHODE	3. CATHODE

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